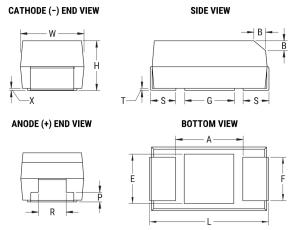


T496B475K025ATE4K0

T496, Tantalum, MnO2 Tantalum, Fused, 4.7 uF, 10%, 25 VDC, SMD, MnO2, Molded, Fused, N/A, 4 Ohms, 3528, Height Max = 2.1 mm



Click here for the 3D model.

Dimensions	,
Footprint	3528
L	3.5mm +/-0.2mm
W	2.8mm +/-0.2mm
Н	1.9mm +/-0.2mm
Т	0.13mm REF
S	0.8mm +/-0.3mm
F	2.2mm +/-0.1mm
A	1.9mm MIN
В	0.4mm +/-0.15mm
E	2.2mm REF
G	1.8mm REF
P	0.4mm REF
R	1.5mm REF
X	0.1mm +/-0.1mm

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	2000

General Information	
Series	T496
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Fused
Features	Integral Fuse
RoHS	Yes
Termination	Tin
AEC-Q200	No
Component Weight	107.45 mg
Shelf Life	156 Weeks
MSL	1

Specifications	
Capacitance	4.7 uF
Capacitance Tolerance	10%
Voltage DC	25 VDC (85C), 16.75 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	N/A
Resistance	4000 mOhms (100kHz 25C)
Ripple Current	146 mA (rms, 100kHz 25C), 131.4 mA (rms, 85C), 58.4 mA (rms, 125C)
Leakage Current	1.2 uA (5min 25°C)

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